L Number	Hits	Search Text	DB	Time stamp
1	211	257/59.ccls. and (insulator or dielectric or	USPAT;	2003/02/28 09:50
-		insulating) near6 (low adj k or low near	US-PGPUB;	, ,
		dielectric or organic or polymer or	EPO; JPO;	
		polyimide or sog or benzocyclobutene or bcb)	DERWENT;	
		and (liquid near crystal or lcd)	IBM_TDB	
15	202	257/72.ccls. and (insulator or dielectric or	USPAT;	2003/02/28 09:54
		insulating) near6 (low adj k or low near	US-PGPUB;	
		dielectric or organic or polymer or polyimide or sog or benzocyclobutene or bcb)	EPO; JPO; DERWENT;	
		and (liquid near crystal or lcd)	IBM_TDB	
22	10		USPAT;	2003/02/28 09:58
		insulating) near6 (low adj k or low near	US-PGPUB;	
		dielectric or organic or polymer or	EPO; JPO;	
		polyimide or sog or benzocyclobutene or bcb)	DERWENT;	
		and (liquid near crystal or lcd)	IBM_TDB	
29	19		USPAT;	2003/02/28 10:03
		insulating) near6 (low adj k or low near	US-PGPUB;	
		dielectric or organic or polymer or polyimide or sog or benzocyclobutene or bcb)	EPO; JPO; DERWENT;	
		and (liquid near crystal or lcd)	IBM TDB	
36	12		USPAT;	2003/02/28 10:03
		insulating) near6 (low adj k or low near	US-PGPUB;	, ,
1		dielectric or organic or polymer or	EPO; JPO;	
		polyimide or sog or benzocyclobutene or bcb)	DERWENT;	
1		and (liquid near crystal or lcd)	IBM_TDB	0000/00/05
-	260		USPAT;	2003/02/27 13:31
		(insulating or insulator or planarization or	US-PGPUB;	
		planar or separating or spacer) near4 (low or high or reduced or reduce or decrease or	EPO; JPO; DERWENT;	·
	1	small or decreased) near2 (dielectric or k	IBM_TDB	
		or capacitive or capacitance)		
-	36		USPAT	2003/02/27 09:32
		"4943838" "5003356" "5045905"		
		"5072262" "5177588" "5229644"		
		"5246782" "5281546" "5287208"		
	,	"5294820" "5408345" "5411629" "5456566" "5475756" "5406463"		
		"5459596" "5477359" "5486493" "5500750" "5576630" "5585951"		
		"5500750"		
		"5675187" "5721596" "5721601"		
		"5724111" "5780874" "5821621"		
		"5844647" "5847720" "5920084"		
		"5994721" "6038008" "6100954").PN.		((
	23	("4980002" "5003356" "5055899"	USPAT	2003/02/27 09:35
		"5182620" "5246782" "5287208" "5302987" "5364547" "5409777"		
		"5302987" "5364547" "5409777" "5414278" "5414547" "5419991"		
		"5422293" "5426523" "5446562"		
		"5453857" "5457553" "5459596"		
		"5463230" "5463484" "5483366"		
		"5528209" "5682211").PN.		
-	15		USPAT	2003/02/27 13:15
		"5229644" "5246782" "5294820" "5406402" "5505051" "55050		
		"5486493" "5585951" "5591676" 		
		"5641974" "5675187" "5721596" "5721601" "5780121" "5821621").PN.		
_	225		USPAT;	2003/02/27 13:23
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	0000/00/00 55 55
-	1560	(liquid adj crystal or lcd) and pixel and	USPAT;	2003/02/27 13:35
		(insulating or insulator or planarization or	US-PGPUB; EPO; JPO;	
		planar or separating or spacer) near4 (organic or benzocyclobutene or bcb)	DERWENT;	
		(organic or benzocycrobatene or beb)	IBM TDB	
-	1448	(liquid adj crystal or lcd) and pixel and	USPAT;	2003/02/27 13:37
		(insulating or insulator or planarization or	US-PGPUB;	
		planar) near4 (organic or benzocyclobutene	EPO; JPO;	
†		or bcb)	DERWENT;	
L			IBM_TDB	<u></u>

-	932		USPAT;	2003/02/27 13:38
		(insulating or insulator or planarization or	US-PGPUB;	
		planar) near4 (organic or benzocyclobutene	EPO; JPO;	
		or bcb)) and tft and gate and drain and	DERWENT;	
]	source	IBM TDB	
_	633	257/57.ccls.	USPAT;	2003/02/27 15:26
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	4		IBM TDB	
_	49	257/57.ccls. and (insulator or dielectric or	USPAT;	2003/02/28 09:46
		insulating) near6 (low adj k or low near	US-PGPUB;	, ,
		dielectric or organic or polymer or	EPO; JPO;	
		polyimide or sog or benzocyclobutene or bcb)	DERWENT;	
			IBM TDB	
_	46	349/44.ccls. and (insulator or dielectric or	USPAT;	2003/02/27 16:18
	1	insulating) near6 (low adj k or low near	US-PGPUB;	2003, 02, 2, 20.10
		dielectric or organic or polymer or	EPO; JPO;	
		polyimide or sog or benzocyclobutene or bcb)	DERWENT;	
		polylimide of sog of belizocyclobatelle of bcb/	IBM TDB	
	11	349/46.ccls. and (insulator or dielectric or	USPAT;	2003/02/27 16:19
_	11	insulating) near6 (low adj k or low near	US-PGPUB;	2003/02/27 10:13
		dielectric or organic or polymer or	EPO; JPO;	
		polyimide or sog or benzocyclobutene or bcb)	DERWENT;	
		polylimide of sog of benzocyclobutene of bcb)	IBM TDB	
_	10	349/47.ccls. and (insulator or dielectric or	USPAT;	2003/02/27 16:20
1 -	10	insulating) near6 (low adj k or low near	US-PGPUB;	2003/02/27 10.20
		dielectric or organic or polymer or	EPO; JPO;	
		polyimide or sog or benzocyclobutene or bcb)	DERWENT;	
		polylillae of sog of benzocyclobatene of bcb/	IBM TDB	
	224	349/138.ccls. and (insulator or dielectric	USPAT;	2003/02/27 16:23
_	224	or insulating) near6 (low adj k or low near	US-PGPUB;	2003/02/2/ 16:23
		dielectric or organic or polymer or	EPO; JPO;	
			1	
		polyimide or sog or benzocyclobutene or bcb)	DERWENT;	
1,	41	240/120 gala and /inquistor or dislactric	IBM_TDB	2003/02/27 16:27
1	41	,,	USPAT;	2003/02/2/ 16:2/
İ		or insulating) near6 (low adj k or low near	US-PGPUB;	·
		dielectric)	EPO; JPO;	
			DERWENT;	
		(3-4 3224 -42	IBM_TDB	1 2002 (02 (22 16 22
8	44		USPAT;	2003/02/27 16:30
1	1	aperture and (capacitance) near4 ((electrode	US-PGPUB;	
		and line) or overlap)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	